	REVISIONS		
LTR	DESCRIPTION	DATE	APPROVED
Α	Added vendor CAGE 01295 with device types 04 - 07 complete revision.	7 Oct 83	N. A. Hauck
В	Added vendor CAGE 34335 to device types 01, 02, 03, 06, and 07. Added device types 08, 09, 10. Device types 04 and 05 not available from an approved source. Inactivated device types 01, 02, and 03 for DIP package for new design.	20 Jan 86	N. A. Hauck
С	Change limits of toff and trimw. Editorial changes throughout.	23 May 86	R. P. Evans
D	Added vendor CAGE 6Y440 with device types 04 and 05. Changed to military drawing format.	28 Apr 87	N. A. Hauck
Е	Changes in accordance with NOR 5962-R157-96.	96-06-26	M. A. Frye
F	Updated boilerplate. Added provisions for the supply of QD certified parts to the drawing. Added CAGE 3V146 to drawing glg	00-12-22	Raymond Monnin

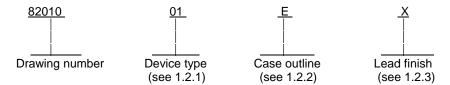
THE ORIGINAL FIRST PAGE OF THIS DRAWING HAS BEEN REPLACED.

CURRENT CAGE CODE IS 67268.

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REV																			
SHEET	F	F	F	F	F														
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SHEET																			
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AND AGEN DEPARTMEN			_	DRA	WING	DVAL D													
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									SHE	ET		1	OF	19					

1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.
 - 1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 <u>Device types</u>. The device types shall identify the circuit functions as follows:

Device type	Generic number 1/	<u>Circuit</u>	Access time	<u>Refresh</u>
01		65,536 X 1-bit RAM	150 ns	128 cycles (1 ms)
02		65,536 X 1-bit RAM	150 ns	128 cycles (2 ms)
03		65,536 X 1-bit RAM	200 ns	128 cycles (2 ms)
04		65,536 X 1-bit RAM	150 ns	256 cycles (4 ms)
05		65,536 X 1-bit RAM	200 ns	256 cycles (4 ms)
06		65,536 X 1-bit RAM	150 ns	256 cycles (4 ms)
07		65,536 X 1-bit RAM	200 ns	256 cycles (4 ms)
08		65,536 X 1-bit RAM	120 ns	256 cycles (4 ms)
09		65,536 X 1-bit RAM	150 ns	128 cycles (2 ms)
10		65,536 X 1-bit RAM	200 ns	128 cycles (2 ms)

1.2.2 Case outlines. The case outlines shall be as designated in MIL-STD-1835, and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
E	GDIP1-T16 or CDIP2-T16	16	dual-in-line package
Ζ	CQCC3-N18	18	rectangular chip carrier package

1.3 Absolute maximum ratings.

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^{1/} Generic numbers are listed on the Standard Microcircuit Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-HDBK-103 and QML-38535, as applicable (see 6.6 herein).

1.4 Recommended operating conditions.

Supply voltage	4.5 V dc to 5.5 V dc
Maximum low-level input voltage (V _{IL}):	
Device types 01, 02, and 03	-1.5 V dc to 0.8 V dc
Device types 04, 05, 06, 07, and 08	-0.6 V dc to 0.8 V dc
Device types 09 and 10	-1.0 V dc to 0.8 V dc
Maximum high-level input voltage (V _{IH}):	
Device types 01, 02, and 03	2.4 V dc to 6.5 V dc
Device types 04, 05, 06, 07, and 08	
Device types 09 and 10	2.4 V dc to V_{CC} +1.0 V dc
Refresh cycle time:	
Device type 01	1.0 ms
Device types 02, 03, 09, and 10	
Device types 04, 05, 06, 07, and 08	4.0 ms
Case operating temperature range:	
Device types 01, 02, 03, 06, 07, 08, 09,	
and 10	-55°C to +110°C
Device types 04 and 05	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard Microcircuits. MIL-STD-973 - Configuration Management.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

HANDBOOKS

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's).

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

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3. REQUIREMENTS

- 3.1 <u>Item requirements</u> The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturer's approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used. This drawing has been modified to allow the manufacturer to use the alternate die/fabrication requirements of paragraph A.3.2.2 of MIL-PRF-38535 or alternative approved by the Qualifying Activity.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.3 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103 (see 6.6 herein). For packages where the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.
- 3.5.1 <u>Certification/compliance mark</u>. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, Appendix A. For Class Q product built in accordance with A.3.2.2 of MIL-PRF-38535 or other alternative approved by the Qualifying Activity, the "QD" certification mark shall be used in place of the "QML" or "Q" certification mark.
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change</u>. Notification of change to DSCC-VA shall be required in accordance with MIL-PRF-38535, appendix A.
- 3.9 <u>Verification and review</u>. DSCC, DSCC's agent and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
 - 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

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- a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or procuring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
- 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5, 6, 7, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 (C₁, C₂ and C_{OUT} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance. Sample size is 5 devices with no failures, and all input and output terminals tested.

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		Conditions	Group A	Device	Limits		
Test	Symbol	$-55^{\circ}C \le T_{C} \le +110^{\circ}C, \ 1/$ unless otherwise specified	subgroups	type	Min	Max	Unit
High-level output voltage	V _{OH}	$V_{DD} = 5 \text{ V}, V_{IN} = 0 \text{ or } V_{DD}$ $I_{OH} = -5 \text{ mA}$	1, 2, 3	All	2.4		V
Low-level output voltage	V _{OL}	$V_{DD} = 5 \text{ V}, V_{IN} = 0 \text{ or } V_{DD}$ $I_{OL} = 4.2 \text{ mA}$	1, 2, 3	All		0.4	V
Supply current, standby	I _{DD1}	$ V_{DD} = 5 \text{ V}, \overline{CAS} = \overline{RAS} = V_{IH}$ $ D_{OUT} = \text{High } Z$	1, 2, 3	All		5	mA
Supply current, operating	I _{DD2}	$ V_{DD} = 5 \text{ V}, \overline{\text{RAS}} \text{ and } \overline{\text{CAS}} \text{ cycling}$ $ t_{CYC} = t_{RC} \text{ min}$	1, 2, 3	01,02,03,		60	mA
	<u>2</u> /			07,08,09 10		55	+
Supply current,	I _{DD3}	V _{DD} = 5 V, RAS = cycling,	1, 2, 3	01,02,03,		45	mA
RAS only cycle		$\mid t_{CYC} = t_{RC} \text{ min, } \overline{CAS} = V_{IH}$		04,05,06, <u>07,08,09</u>			<u> </u>
		<u> </u>		10		40	
Supply current,	$ I_{DD4} $	RAS = V _{IL} , CAS cycling	1, 2, 3	09		45	⊥ mA
PAGE mode		t _{pc} = min		10		40	
High-level input leakage current	I _{IH}	V _{DD} = 5 V, V _{IN} = 5.0 V	1, 2, 3	All		10	μ A
Low-level input leakage current	I _{IL}	$V_{DD} = 5 \text{ V}, V_{IN} = 0.8 \text{ V}$	1, 2, 3	All		-10	μ A
High-level output	 I _{ОН}	$ V_{DD} = 5 \text{ V}, V_{OUT} = 5.5 \text{ V}$	1, 2, 3	 All		10	 μA
leakage current		RAS = CAS = V _{IH}					
Low-level output	 I _{OL}	V _{DD} = 5 V, V _{OUT} = GND	1, 2, 3	 All		-10	 μΑ
leakage current		$\mid RAS = CAS = V_{IH}$					
Land and the		 	4	01,02,03,			-
Input capacitance (A ₀ - A ₇)	C ₁ <u>3</u> /	T _C = +25°C 	4	<u>09,10</u> 04,05, 06,07,08		5 7 	pF pF
Input capacitance	 C ₂ <u>3</u> /	 T _C = +25°C	4	 01,02,03,		 10	 pF
(RAS, CAS, DIN,				04,05,06,		1	
WE)				07,08	1	1	I
,	į			09,10	i	7	i

See footnotes at end of table.

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		Conditions	Group A	Device	_ Limits	3	1
Test	Symbol	-55°C ≤ T _C ≤ +110°C, <u>1</u> / unless otherwise specified	subgroups	type	Min	Max	Unit
Output capacitance (RAS)	С _{оит} <u>3</u> / 	T _C = +25°C 	4	01,02,03, 04,05,06, 07,08		8	pF
			j	09,10		6	Ĭ
Access time from	 t _{RAC}	 See figure 4	 9, 10, 11	01,02		150	ns
RAS	<u>4</u> / <u>5</u> / 	 		03,05, <u>07,</u> 10		200	 <u> </u>
				08		120	
A				04,06,10		100	<u> </u>
Access time from	t _{CAC}	See figure 4	9, 10, 11	01,02		90	ns
CAS	<u>3</u> / <u>4</u> / <u>5</u> /			03		120	
	[05,07		135	\perp
	[<u> </u>		_08		70	1
-	<u> </u>			09		75	1
Time between	t _{REF}	See figure 4	9, 10, 11	01		1.0	ms
refresh				02,03,09,10		2.0	+
	[[] 		04, 05, 06,07,08		4.0	
	<u> </u> 			06,07,08	160		1
	I .	1	I				+
RAS precharge	t _{RP}	See figure 4	9, 10, 11	01,02,06,09		<u> </u>	⊥ ns
time				03	135		+
				05	200		+
	[[] 		07,10 08	120 80		+
	<u> </u>	<u> </u>		•		-	1
CAS precharge time	t _{CPN}		9, 10, 11	09	30		⊥ ns
(nonpage cycles)	<u> </u>			10	35		
CAS to RAS pre- charge time	t _{CRP}	See figure 4 	9, 10, 11	All	0		ns
	[04	20	50	_
RAS to CAS delay	t _{RCD}	See figure 4	9, 10, 11	01,02,06	30	60	ns
time			,,	03,07	35	80	<u> </u>
	į	İ		05	25	65	Ī
	[İ	_08	15	50	Ţ
	[ļ	ļ	09	30	75	1
	<u> </u>			10	35	100	1
		I		04,06,10	100		
RAS hold time	t _{RSH}	See figure 4	9, 10, 11	01,02	90		⊥ns
	[03	120		\perp
				05,07	135		\perp
				08	60	<u> </u>	<u> </u>
	<u> </u>	<u> </u>		09	75	-	-
	1	I		04,06			1
CAS hold time	t _{CSH}	See figure 4	9, 10, 11	01,02,09	150		⊥ns
				03,05,07,10			1
	ļ			08	120		
See footnotes at end	of table.						
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		Conditions	Group A	Device	Limit	S	L
Test	Symbol	-55°C ≤ T _C ≤ +110°C, <u>1</u> / unless otherwise specified	subgroups	type	Min 	Max 	Unit
Row address setup time	t _{ASR}	 See figure 4	9, 10, 11	01,02,03, 06,07,08, 09,10	 0 		ns
				04,05	5		
				01,02,	<u> </u>	<u> </u>	
Row address hold	t _{RAH}	See figure 4	9, 10, 11	04,06,09	20		⊥ns
time				03,07,10,	25		Ţ
				08	15		
				01,02,03,			
				04,05,09,	0		
Column address	tasc	See figure 4	9, 10, 11	<u>10</u>			⊥ns
setup time				06,07,08	-5		
				04	60		Ţ
Column address	t _{CAH}	See figure 4	9, 10, 11	01,02,09	30		ns
hold time				03,08,10	40		ļ
				05	70		_
				06	45		_
				07	55		
				04,06	95		1
Column address	t _{AR}	See figure 4	9, 10, 11	01,02	100		⊥ ns
hold time, to RAS		I	1	03	130	1	
	i	į	į	05,07,10	140	İ	Ī
	i	į	į	08	85	i	Ī
	İ	İ	İ	09	105	İ	Ī
				01,02,03,	ĺ		İ
Transition time	İt⊤	See figure 4 6/	9, 10, 11	06,07,08,	3	50	ns
	i	<u> </u>	i ' '	09,10	İ	i	i
	i	İ	į	04,05	3	20	Ī
		i		03,04,07,	0	50	İ
	İ	į	j	10	İ	İ	İ
Output buffer	toff	See figure 4 7/	9, 10, 11	01,02	0	40	ns
turn-off delay	İ	<u> </u>	j	06,08,09	0	40	Ĺ
	<u> </u>	<u> </u>	<u>i</u>	05	0	60	
Read and refresh		See figure 4		04	330	1,500	L
cycles:			9, 10, 11	01,02,06	260	10,000	⊥ns
Random read cycle	t _{RC}			03	345	10,000	Ţ
time				05	420	1,500	Ţ
				_07	330	10,000	1
			İ	08	230		Ţ
				09	260		Ţ
				10	330		
				_04	150	1,500	ļ
RAS pulse width	t _{RAS}	See figure 4	9, 10, 11	01,02,06,09	150	10,000	⊥ns
•	İ	İ		03,07,10	200	10,000	Ī
	<u> </u>	İ	i	05	200	1,500	-
	1	1 1	1	08	120	10,000	+

See footnotes at end of table.

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Test Symbol		1	Conditions	Group A	Device	Limit	S	Ī
CAS pulse width CAS See figure 4	Test	Symbol	-55°C <u><</u> T _C <u><</u> +110°C, <u>1</u> /					Unit
Read command set up time twc See figure 4 9, 10, 11 All 0 0 0 0 0 0 0 0 0					_04	100	1,500	
Read command set up time trcs See figure 4 9, 10, 11 All 0 0 0 0 0 0 0 0 0	CAS pulse width	tcas	See figure 4	9. 10. 11	01.02	90	10.000	ns
Read command set- tracs See figure 4 9, 10, 11 All 0								
Read command set up time Read command set up time Read command tach up time Read command tach lime Read command tach lime Read command tach lime Read command tach lime Read command tach lime Write cycle: See figure 4 9, 10, 11 All 0 0		İ	†		I —			Ī
Read command set- up time Read command set- up time Read command hold time Write cycle: Random write cycle time See figure 4 9, 10, 11 All 0 0 0 0 75 10,000 0 0 75 10,000 0 0 10 10 10 10 10 10		İ	i					Ī
Read command set- Up time Read command Rech See figure 4 9, 10, 11 All 0 Up time Read command Rech See figure 4 9, 10, 11 All 0 Write cycle:		İ	İ					Ī
See figure 4 See	į	İ	İ	į	09	75	10,000	Ī
Mode Mode		t _{RCS}	See figure 4	9, 10, 11	All	0		ns
Write cycle: See figure 4 9, 10, 11 07 330 10,000 Random write cycle time 1		t _{RCH}	See figure 4	9, 10, 11	All	0		ns
Random write cycle time								⊥
cycle time 03 345 10,000 .05 420 1,500 .08 230 .09 260 .09 260 .10 .330 .09 .260 .10 .330 .01 .03 .03 .00 .00 .04,05,06,07 .08 .5 .09,10 .10 .00 .00 .09 .04,06 .60 .00 .00 .04,06 .60 .00 .00 .04,06 .60 .00 .00 .05,07 .80 .00 .00 .05,07 .80 .00 .00 .03 .55 .00 .05,07 .80 .00 .00 .00 .09 .35 .00 .00 .09 .35 .00 .00 .00 .00 .00 .00 .00 .00 .00 .00 .00 .0	Write cycle: Random write		See figure 4	j	07	330	10,000	L
		t _{WC}		9, 10, 11				⊥ ns
Note that the command See figure 4 See figure	cycle time							L
Write command setup time	 					-	1,500	Ţ
Write command setup time twcs See figure 4 9, 10, 11 01,02,03, 0 0 04,05,06,07 0 08 08 0.5 09,10 0.10 0.10 0.10 0.10 0.10 0.10 0.10 0								L
Write command setup time twcs See figure 4 9, 10, 11 01,02,03, 0 0 04,05,06,07 0 08 -5 009,10 -10 09,10 -10 009,10 -10 009,10 -10 004,06 60 00 009,10 -10 004,06 60 00 009,10 -10 004,06 60 00 009,10 -10 009,10 -10 009,10 -10 009,10 -10 009,10 -10 009,10 -10 009,10 -10 009,			ļ					Ļ
Setup time								
Write command twch See figure 4 9, 10, 11		t _{wcs} 	See figure 4 	9, 10, 11 	04,05,06,07			∣ ns ⊥
Write command hold time See figure 4 9, 10, 11 04,06 60 01,02,10 45 03 55 05,07 80 08 40 09 35 09 35 000								L
Write command hold time twch See figure 4 9, 10, 11 01,02,10 45 03 55 05,07 80 0 08 40 09 35 04 125 04 125 04 125 0						-		
hold time 03 55 05,07 80 08 40 09 35 04 125 03 150 03 150 06,09 110 07,10 145 08 85 01,02 08 85 01,02 08 85 01,02 03 04,06 60 09 35 04,06 60 04								Ļ
Write command twcr See figure 4 9, 10, 11 01,02 120 07,10 145 08 85 01,02 08 85 01,02 03 05,07 55 08 25 09 35 04,06 60 04,06,10 45 04,06 60 04,06,10 45 04,06 60 04,06 60 04,06 60 04,06 60 04,06 60 04,06,09 10,02 04,06 60		t _{WCH}	See figure 4	9, 10, 11				_ ns
Write command twcr See figure 4 9, 10, 11 01,02 120 150 160 100,000 110 100,000 110 100,000 110 100,000 110 100,00	noid time		ļ					Ļ
Write command twcr See figure 4 9, 10, 11 01,02 120 03 150 04 125 03 150 05 160 06,09 110 07,10 145 08 85 01,02 08 01,02 08 01,02 09 09 09 09 09 09 09								Ļ
Write command hold time to twcr See figure 4 9, 10, 11 04 125 120 120 120 120 150								Ļ
Write command hold time to twcR See figure 4 9, 10, 11 01,02 120		<u> </u>	1					
RAS 03 150 RAS 05 160 06,09 110 07,10 145 08 85 01,02 Write command pulse width 9, 10, 11 04,06,10 45 08 25 09 35 09 35 04,06 60 Write command to t _{RWL} See figure 4 9, 10, 11 01,02,09 45	Write command	l I two	 See figure 4	 9 10 11			+	⊥ ∣ns
RAS 05 160 06,09 110 07,10 145 08 85 Write command twp See figure 4 9, 10, 11 04,06,10 45 09 35 09 35 Write command to t_RWL See figure 4 9, 10, 11 01,02,09 45 01,02 03,05,07 55 08 25 09 35 04,06 60 01,02,09 45		WCR	Oce ligure	0, 10, 11				⊥ ''3
Write command twp See figure 4 9, 10, 11 01,02 03,05,07 55 08 25 09 35 04,06 60 04,06 60 04,06,09 45 01,02,09 01,02,00 01,02,00 01,02,00 01,02,00 01,02,00 01,02,00 01,02,00 01,02,00 01,02,00		1	1	l I			1	±
Write command twp See figure 4 9, 10, 11 04,06,10 45 08 25 09 35 04,06 60 01,02,09 45 01,02,00 45 01,02,09 45 01,02,00 45 01,02,00 45 01,02,00 4	KAS		Į.				1	Ļ
Write command twp See figure 4 9, 10, 11 04,06,10 45 03,05,07 55 08 25 09 35 04,06 60 04,06							<u> </u>	Ļ
Write command pulse width Image: square depicted by the pulse							<u> </u>	Ļ
Write command pulse width twp See figure 4 9, 10, 11 04,06,10 45 03,05,07 55 08 25 09 35 09 35 04,06 60 00 04,06 60 00 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 01,02,09 45 02,02,03 03,05,07 55 02,02,03 03,05,07 55 02,02,03 03,05,07 55 03,05,07 50 03,05,07						85		<u> </u>
pulse width 03,05,07 55 08 25 09 35 09 35 04,06 60 09 00,05	Write command	 t=	See figure 4			 16		
08 25 09 35		ι WΡ 	See ligule 4 	9, 10, 11			+	⊥ ns
Write command to t _{RWL} See figure 4 9, 10, 11 01,02,09 45		 	I I	l I				
Write command to t_RWL See figure 4 9, 10, 11 01,02,09 45 10, 11 45 10,02,09 45 10,02,09 45 10,02,09 45 10,02,09 45 10,02,09 45 10,02,09 <		 	I 					<u>+</u>
Write command to tRWL See figure 4 9, 10, 11 01,02,09 45							+	<u> </u>
	Write command to	l I t _{RWI}	See figure 4	9. 10. 11				⊥ ∣ns
RAS lead time		-1744F	1 - 20	, , , , , , , ,	•		+	<u>.</u>
· · · · · · · · · · · · · · · · · · ·	RAS lead time	!	Į.	ļ				Ļ
05,07 80			ļ.	ļ				Ļ
			1		08	50		

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		82010
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		Conditions	Group A	Device	Limit	S	L
Test	Symbol	-55°C ≤ T _C ≤ +110°C, <u>1</u> / unless otherwise specified	subgroups	type	Min	Max 	Unit
				04,06	60		<u> </u>
Write command to	t _{CWL}	See figure 4	9, 10, 11	01,02,09	45	1	⊥ ns
CAS lead time	1	I	1	03,10	55	1	
				05,07	80	i	-
				08	50	İ	Ī
Data-in setup time	 t _{DS}	 See figure 4	9, 10, 11	 All	0		 ns
				04,06	60	İ	
Data-in hold time	t _{DH}	See figure 4	9, 10, 11	01,02,10	45	İ	ns
	j	į	İ	03	55		Ī
			j	05,07	80		Ţ
				08	40		Ţ
				09	35		L
				04	125		Ţ
Data-in hold time,	$ t_{DHR} $	See figure 4	9, 10, 11	01,02	120		⊥ ns
to RAS	1	I	1	03	150	1	I
				05	160	i	-
	İ		i	06,09	110	i	Ť
	İ	<u> </u>	į	07,10	145	i	-
	i	į	į	08	85		Ī
			İ	01,02	280	10,000	Ĺ
Read modify write	t _{RMW}	See figure 4	9, 10, 11	04	345	1,500	
cycle time				05	425	1,500	L
				06	285	10,000	
			ļ	08	260	10,000	⊥ns
			ļ	03	370	10,000	Ļ
			ļ	07	345	10,000	Ļ
				09	280		Ļ
				10	345	<u> </u>	
				04,06	110	-	Ļ
RAS to WE delay	t _{RWD}	See figure 4	9, 10, 11	01,02,09	120		⊥ns
				03	165		L
		ļ	ļ	05,07	130	<u> </u>	Ļ
				08	85	-	Ļ
	 	1		10	155	 	
	I	I	I	04,06	60	1	T
CAS to WE delay	t _{CWD}	See figure 4	9, 10, 11	01,02,10	55		⊥ns
-				03	80		Ţ
j I				05,07	65		L
				08	40		L
	<u> </u>			09	45	1	
Read command				01,02,04,05		ļ	Ļ
nold time	t _{RRH}	See figure 4	9, 10, 11	03	25		⊥ns
referenced to RAS	1	1		06,07,08	5	1	I
referenced to RAS	1	i .	1	1 			-

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000

STANDARD

MICROCIRCUIT DRAWING

SIZE
A

REVISION LEVEL
F

SHEET
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		Conditions	Group A	Device	Limits		T
Test	Symbol	-55°C ≤ T_C ≤ +110°C, 1/ unless otherwise specified	subgroups	type	Min	Max 	Unit
Page mode read	 t _{PC}	 See figure 4	9, 10, 11	09	145	<u> </u>	ns
or write cycle				10	190		
CAS precharge	l ∣t _{CP}	See figure 4	 9, 10, 11	09	60		⊥ ns
time, page mode				10	80		

- 1/ Device types 04 and 05, $T_C = -55$ °C to +125°C.
- Z/ I_{DD} is dependent on output loading and cycle rates. The I_{DD} measurements are made with the outputs open. Limits are for cycle rates listed in condition column and worst case data pattern (alternate "1" and "0") at a PRR = 4.0 MHz. T_{CYC} = T_{RC} min.
- 3/ Capacitance measured with Boonton meter or equivalent or effective capacitance calculated from the equation $C = \underline{I\Delta t}$ with ΔV equal to 3 volts and $V_{CC} = 5.0 \text{ V}$.
- 4/ Load = One Schottky TTL +100 pF or equivalent for device types 01, 02, and 03.
- $\frac{5}{2}$ Load = Two Schottky TTL +100 pF or equivalent for device types 04, 05, 06, 07, 08, 09, and 10.
- 6/ Devices are tested at $t_T = 5$ ns, where t_T is the rise and fall time for RAS and CAS.
- 7/ Tested only initially and after any design changes.

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Device types	All			
Case outlines	E	Z		
Terminal number	Termina	l symbol		
1	NC	NC		
2	D _{IN}	D _{IN}		
3	WE	WE		
4	RAS	RAS		
5	A_0	NC		
6	A_2	A_0		
7	A_1	A_2		
8	V_{DD}	A_1		
9	A ₇	V_{DD}		
10	A ₅	A ₇		
11	A_4	A ₅		
12	A ₃	A_4		
13	A ₆	A ₃		
14	D _{OUT}	NC		
15	CAS	A ₆		
16	V_{SS}	D _{OUT}		
17		CAS		
18		V_{SS}		

FIGURE 1. <u>Terminal connections</u>.

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Truth Table						
		OUTPUT				
Operation 7/	RAS	CAS	D _{IN}	Address	Write	D _{OUT} <u>1</u> /
Chip not selected	Н	Н	X <u>2</u> /	X	Х	High Z
Write "L" in cell A _{xy} 3/	L	L	L	A _{xy}	L	High Z <u>4</u> /
Write "H" in cell A _{xy}	L	L	Н	A _{xy}	L	High Z <u>4</u> /
Read data in cell A _{xy}	L	L	Х	A _{xy}	Н	Data (A _{xy})
RAS only refresh	L	Н	Х	A _x <u>5</u> /	Х	High Z
Hidden RAS only refresh	L	L	Н	A _X	Н	Data (A _{x-N,y-N}) 6/

NOTES:

- $\underline{1}$ / D_{OUT} is not inverted from D_{IN} .
- 2/ "X" = Don't care.
- $3/A_{XY}$ denotes proper address logic to address cell A_{XY} .
- 4/ For "EARLY WRITE" timing, data out remains at high impedance. For "LATE WRITE" timing, data out is valid from access time to the beginning of a subsequent cycle, or until CAS goes to a high level.
- $5/A_X$ depends only on A_0 - A_6 ; A_7 is a don't care.
- $\underline{6}$ / When CAS = V_{IL}, the data output will contain data from the last valid read cycle (i.e., N cycles before).
- $\underline{7}$ / A 500 μ s pause and eight initialization cycles required before truth table applies. All timing requirements shall be applied.

FIGURE 2. Truth table.

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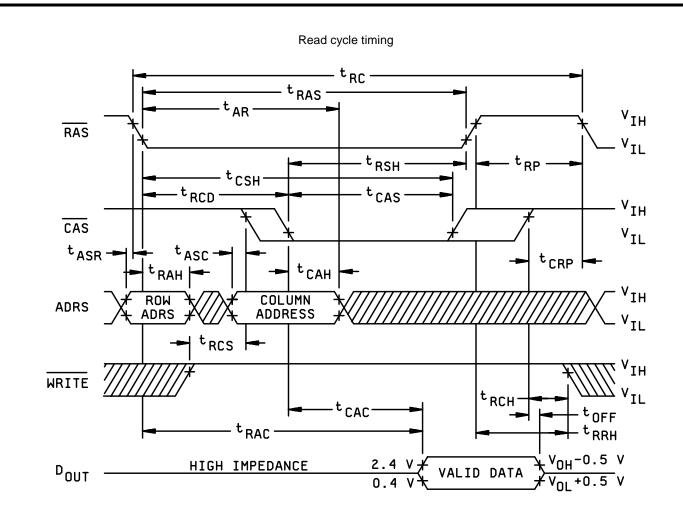


FIGURE 4. Switching waveforms.

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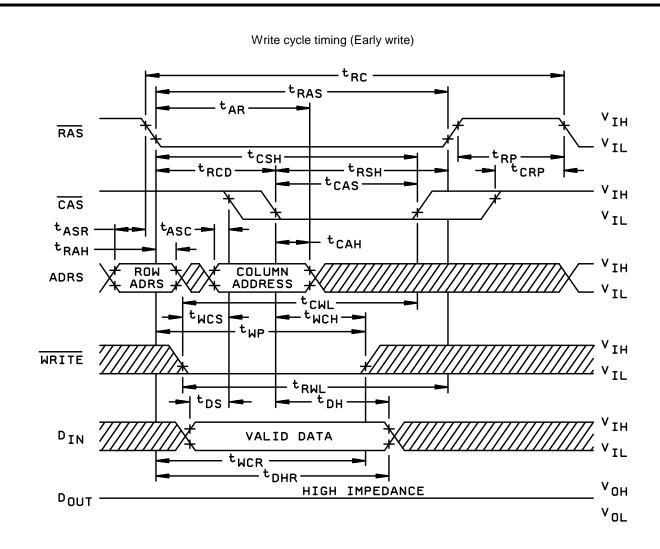


FIGURE 4. <u>Switching waveforms</u> - Continued.

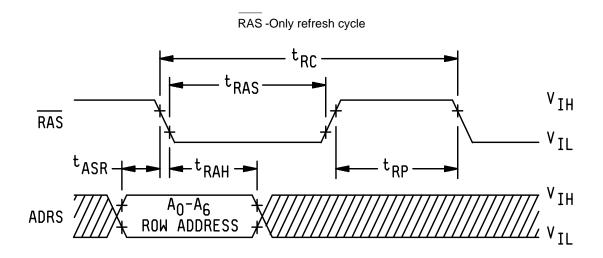
STANDARD MICROCIRCUIT DRAWING	SIZE A		82010
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Read/write - read/modify/write cycle - t_{RMW} - t_{RAS} t_{AR} v_{IH} RAS v_{IL} t_{CSH} ${}^{\rm t}{\rm RCD}$ t_{CRP} ${}^{\rm t}$ RSH tCAS v_{IH} CAS $v_{\rm IL}$ $^{\mathrm{t}}$ CAH v_{IH} COLUMN ADDRESS VIL $^{\rm t}_{\rm RWD}$ tcwD v_{IH} WRITE v_{IL} ^tCAC HIGH IMPEDANCE 2.4 V $^{\mathrm{D}}\,\mathrm{out}$ _ t_{DH} t_{RAC}t_{DS}-

VALID DATA

FIGURE 4. Switching waveforms - Continued.

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Notes:

- 1. $\overline{CAS} = V_{IH}$; \overline{WRITE} , D_{IN} , A_7 don't care.
- 2. DOUT high impedance.

FIGURE 4. <u>Switching waveforms</u> - Continued.

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Page mode cycle timing t_{RAS} -RAS t_{PC} ^tRSH t_{CP} t_{CSH} t_{CRP} tCAS t_{RCD} CAS t_{RAH}-XXXCOLUMNXXXXXXX ADDRESS t_{OFF} toff $^{\mathrm{t}}\mathrm{CAC}$ t_{RAC} DO ^tWCH t_{WCR} tRCS -^tRCH ^tCWL t_{RCH} -WE - t_{DH} t_{DS}-INPUT STABLE - ^tDHR

FIGURE 4. Switching waveforms - Continued.

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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition D or E. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or procuring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

	Subgroups (per
MIL-STD-883 test requirements	method 5005, table I)
Interim electrical parameters	
(method 5004)	
Final electrical test parameters	1*, 2, 3, 9,
(method 5004)	10, 11
Group A test requirements	1, 2, 3, 4, 9,
(method 5005)	10, 11
Groups C and D end-point	1, 9
electrical parameters (method 5005)	

^{*}PDA applies to subgroup 1.

5. PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.
- 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0525.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone 614-692-0674.
- 6.6 <u>Approved source of supply</u>. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 00-12-22

Approved sources of supply for SMD 82010 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revisions of MIL-HDBK-103 and QML-38535.

Microcircuit	Vendor	Vendor
drawing part	CAGE	similar part
number <u>1</u> /	number	number 2/
	<u>3</u> /	AM9064-15L/BEA
8201001EA	18778	MKB4564P-82
8201001ZX 	<u>3</u> /	MKB4564E-82
	<u>3</u> /	AM9064-15L/BEA
8201002EA	18778	MKB4564P-82
8201002ZX	<u>3</u> /	MKB4564E-82
	<u>3</u> /	AM9064-20L/BEA
8201003EA	18778	MKB4564P-83
8201003ZX	3/	MKB4564E-83
8201004EX	3/	MT4264C-15
8201004ZX	3/	MT4264EC-15
8201005EX	3/	MT4264C-20
8201005ZX	3/	MT4264EC-20
8201006EA	3V146	4164-15JDS/BEA
	3/	AM9064-15L/BEA
	3/	SMJ4164-15JDS
8201006ZX	<u>3</u> /	SMJ4164-15FGS
8201007EA	3V146	4164-20JDS/BEA
	<u>3</u> /	AM9064-20L/BEA
	3/	SMJ4164-20JDS
8201007ZX	<u>3</u> /	SMJ4164-20FGS
 8201008EA	3V146	4164-12JDS/BEA
	3/	SMJ4164-12JDS
8201008ZX	<u>3</u> /	SMJ4164-12FGS
8201009EX	<u>3</u> /	AM9064-15L/BEA
8201010EX	<u>3</u> /	AM9064-20L/BEA
I 		

^{1/} The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the Vendor to determine its availability.

^{2/ &}lt;u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

^{3/} No longer available from an approved source.

STANDARD MICROCIRCUIT DRAWING BULLETIN - continued.

Vendor CAGE number	Vendor name <u>and address</u>
18778	Thomson Components and Tubes Corp. 40G Commerce Way Totowa, NJ 07511-0540 Point of contact: Atmel Grenoble Avenue De Rochepleine Saint Egreve F-38120, France
3V146	Rochester Electronics Inc. 10 Malcolm Hoyt Drive Newburyport, MA 01950

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin.